# **SPDT RF Switch**

## **ZSW2-272VHDR+**

50  $\Omega$  Reflective RF switch 30 to 2700 MHz Internal driver, Single Supply Voltage 2.3V to 3.6V

# The Big Deal

- High power 20W
- Low loss, 0.35 up to 1 GHz
- High linearity, IP3 +85 dBm@850 MHz



Model No.	ZSW2-272VHDR+	ZSW2-272VHDRX+ <sup>Δ</sup>
With Bracket	ZSW2-272VHDRB+	ZSW2-272VHDRXB+ <sup>Δ</sup>
Case Style	Q\	V2427
Connectors	9	SMA

 $\Delta$  For ZSW2-272VHDRX+ heat sink not included. Alternative heat sinking and heat removal must be provided by the user to limit maximum base-plate temperature to 85°C, in order to ensure proper performance.

#### +RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

# **Applications**

- Lab
- Instrumentation
- Automatic Test equipment (ATE)
- Base station
- Defense

## **Product Overview**

Mini-Circuits' ZSW2-272VHDR+ is a 50  $\Omega$  high power SPDT RF switch covering a broad frequency range from 30 to 2700 MHz with low insertion loss, and very high linearity.

The ZSW2-272VHDR+ operates on a single supply voltage from +2.3 V to +3.6 V with single pin control. The ZSW2-272VHDR+ comes in a rugged package and is available both with heatsink (2.025" x 1.63" x 1.89") and without heatsink (2.0" x 1.5" x 0.6").

# **Key Features**

Feature	Advantages
Wideband, 30 to 2700 MHz	One model can be used in many applications, saving component count. Also ideal for wideband applications such as military and instrumentation.
High power: • 20W up to 2000 MHz • 16W up to 2700 MHz	Suitable for signal routing applications with high power requirement such as antenna feeds in transmit systems and more.
Low insertion loss:  • 0.35 dB up to 1000 MHz  • 0.50 dB up to 2000 MHz	Provides excellent transmission of signal power from input to output and minimizes overall system loss
High linearity, +85 dBm IP3	High linearity minimizes unwanted inter-modulation products which are difficult or impossible to filter in multi-carrier environments, or in the presence of strong interfering signals from adjacent circuitry received by the antenna.



### RF Electrical Specifications: 30-2700 MHz, TAMB=25°C, VDD=+3.3V (unless noted otherwise)

Parameter	Port	Frequency	Min.	Тур.	Max.	Units
Operating Frequency	_	_	30	_	2700	MHz
Insertion Loss	_	30-1000 MHz 1000-2000 MHz 2000-2700 MHz	1000-2000 MHz —			dB
Isolation	between RF COM and inactive ports	30-1000 MHz 1000-2000 MHz 2000-2700 MHz	32 25 21	40 30 24	_	dB
Isolation	between RF1 and RF2 ports	30-1000 MHz 1000-2000 MHz 2000-2700 MHz	34 27 23	42 33 28	_	dB
VSWR	RF COM port	30-1000 MHz 1000-2000 MHz 2000-2700 MHz	_	1.15 1.25 1.35	_	:1
VSWN	RF1/RF2 active port	30-1000 MHz 1000-2000 MHz 2000-2700 MHz	_	1.15 1.25 1.35	_	:1
Harmonics@ +15 dBm input power	_	30 - 2700 MHz	30 - 2700 MHz —		_	dBc
Non Harmonic Spurs	_	_	_	-124	_	dBm
Input 0.1dB Compression <sup>1</sup>	RF COM to any active port	30-2000 MHz 2000-2700 MHz	_	+45.5 +44.5	_	dBm
IP3 <sup>2</sup>	RF COM to any active port	850 MHz 2700 MHz	_	85 81	_	dBm
	CW (cold switching) <sup>3</sup>	30-2000 MHz 2000-2700 MHz	_	_	43 42	dBm
RF Input Power @-40°C to +85°C, case	Pulsed <sup>3,4</sup>	30-2000 MHz 2000-2700 MHz	_	_	44.5 43.5	dBm
temperature	Hot switching	30-2700 MHz	_	_	30	dBm
	Unbiased	30-2700 MHz	_	_	27	dBm

<sup>1. 0.1</sup> dB compression is a measure of linearity. Do not exceed max power ratings (see absolute maximum ratings on next page). 2. IP3 was tested with +39 dBm per tone.

#### **DC Electrical Specifications**

Parameter	Min.	Тур.	Max.	Units
VDD, Supply Voltage	2.3	_	3.6	V
Supply Current <sup>5</sup>	_	0.15	0.5	mA
Control Voltage Low	0	_	0.2xVDD (max 0.6V)	V
Control Voltage High	0.8xVDD	_	5.5	V
Control Current (per pin)	_	15	_	μΑ

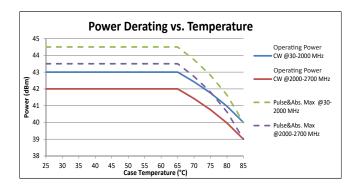
<sup>5.</sup> Supply current may reach 3mA at startup.

#### **Switching Specifications**

Parameter	Conditions	Min.	Тур.	Max.	Units
Switching time 50% trigger to 10/90% signal level	Pulse rate =12.5[kHz], RF freq. =501[MHz]	_	15	25	μs
Video feedthrough@ all ports	Vctrl=0/3V, Duty Cycle= 50%; Freq=12.5 kHz	_	1	_	mVpp
Switching frequency		_	_	12.5	kHz

<sup>3.</sup> Max Power derates at temperatures over +65°C according to derating graph on page 3.

<sup>4.</sup> Refers to peak power, pulse signal used: 10% duty cycle, 4620 µs period.



The RF switch control bit selects the desired switchstate, as shown in **Table 1**: Truth Table.

#### Absolute Maximum Ratings 6,7

Parameter	Ratings			
Operating Temperature, case 8	-40°C to +85°C			
Storage Temperature	-55°C to +100°C			
VDD, Supply Voltage	-5V Min. 3.6V Max.			
Control Voltage	-0.3V Min. 5.5V Max.			
ESD, HBM	Class 1C (Pass 1000V)			
RF input power @-40°C to +65°C, case 8	44.5dBm @ 30-2000MHz			
HE input power @-40°C to +65°C, case°	43.5dBm @ 2000-2700MHz			
RF input power @+65°C to +85°C, case 8	See derating curves			
DC voltage on RF pins @ RF In ≤0 dBm	15V			

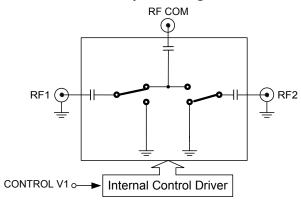
- 6. Operation of this device above any of these conditions may cause permanent damage.
- Operation in the range between the max operating power and the absolute maximum rating for extended periods of time may result in reduced life and reliability.
- Case temperature is defined as the temperature at the base plate the heat sink mounting surface.

Table 1: Truth Table.

STATE	Control Input	RF Input	/ Output
	Control V1	RF COM to RF1	RF COM to RF2
1	Low	OFF	ON
2	High	ON	OFF

Note: V1 is connected to internal pull-up resistor.

#### **Simplified Diagram**



#### Connections

RF1	(SMA female)
RF2	(SMA female)
RF COM	(SMA female)
DC Supply and Control	9 Pin D-Sub female*

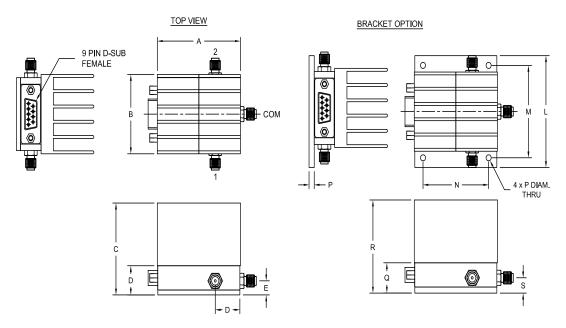
\*9 Pin D-Sub Pin Connections

PIN Number	Function
3	Not Connected
4	Vcontrol
5	VDD
1-2,6-9	GND <sup>9</sup>

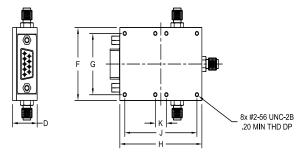
Only one of the GND pins is required to be connected for proper operation.



# **Outline Drawing (QV2427)**



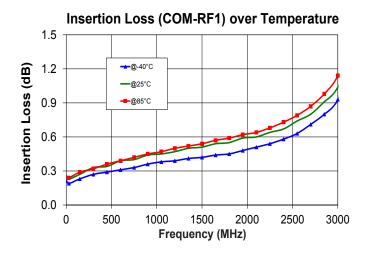
Mounting information for models without heatsink.

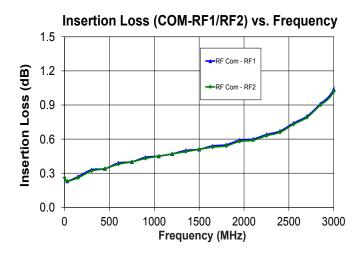


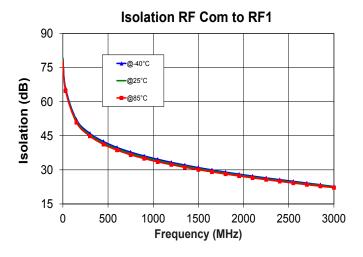
# Outline Dimensions (inch mm)

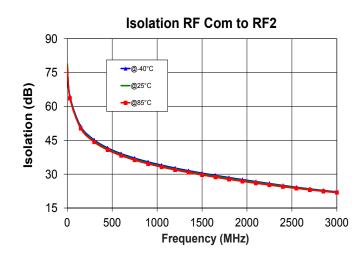
А	В	С	D	E	F	G	Н	J	К	L	М	N	Р	Q	R	S	WT. GRAMS
2.025	1.63	1.89	.600	.29	1.500	1.260	2.000	1.760	0.270	2.30	1.900	1.600	.125	.625	1.915	.315	150
51.44	41.4	48.0	15.24	7.37	38.10	32.0	50.80	44.7	6.86	58.4	48.3	40.6	3.18	15.9	48.64	8.0	100

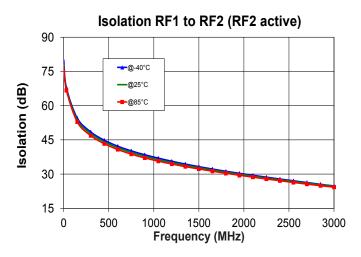
#### **Typical Performance Curves**



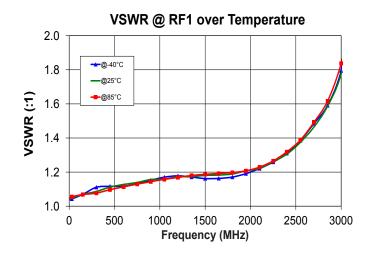


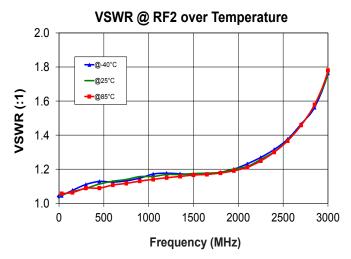


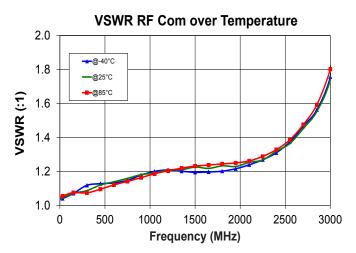




#### **Typical Performance Curves (Continued)**







#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms");
  Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at <a href="https://www.minicircuits.com/MCLStore/terms.jsp">www.minicircuits.com/MCLStore/terms.jsp</a>

